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European Workshop on Photocathodes for Accelerator Applications (EWPAA 2024) Dresden, Germany, 17-19 September 2024



# Outline

- Background
- Photocathode systems
- Photocathode preparation
- Photocathode tests
- Summary



## Background

• SHINE: Shanghai HIgh repetitioN rate XFEL and Extreme light facility

- Linac: 1 MeV electron source, 8 GeV CW SRF linac
- **Undulator:** FEL I/II/III (0.4-25 keV)
- End station: 10
- **Cryogenic plant:** 4kW\*3@2K



3

# Background

SHINE injector layout



# Background

### Ideal photocathode:

- High QE (>1%)
- Long lifetime (~months)
- Short response time (sub ps)
- Low thermal emittance ( $<1\mu$ m/mm)
- Low dark current

### Current SHINE cathode

•  $Cs_2Te$ 

	GaAs-Cs/O	K <sub>2</sub> CsSb	Cs <sub>2</sub> Te
Wavelength	Green (532nm)	Green (532nm)	UV (266nm)
Fresh QE	>10%	>5%	>10%
Gun type	DC,SRF	DC,NCRF,SRF,DC -SRF	NCRF(VHF),S RF, DC-SRF
Vacuum requirement	~10 <sup>-9</sup> Pa	~10 <sup>-8</sup> Pa	~10 <sup>-7</sup> Pa
Response time	~10ps	~lps	~1ps
Operational lifetime	hours~days	days~weeks	weeks~months
Laboratory	Jlab, Cornell University, KEK, BNL	BNL, LBNL(APEX), Jlab, Cornell University	INFN-LASA, DESY, SLAC, FNAL, CERN, ANL, KEK



### **Photocathode systems**



Photocathode preparation system

Photocathode load lock system



### **Photocathode preparation system**





#### Mo substrate(INFN type)



Cs or Te evaporation source

# **Photocathode preparation system**

### Some features of the photocathode preparation system

- The distance between source and substrate is adjustable (2-10cm)
- The deposition thickness and rate of evaporation source can be measured in real time.
- The substrate can be heated and cooled quickly.
- Both positive and negative voltage collect electrons.
- Sequential deposition and co-evaporation of two elements





**Te, Cs sequential deposition** 







Te intermittent, Cs continuous deposition



- Chemical cleaning
- Vacuum heat cleaning

• Te,Cs degas

Substrate treatment

Te intermittment,Cs

continuous

deposition

- 1nm Te deposition(@100°C)
- Cs deposition until the first maximum QE (@100°C, 10µW 265nm)
- Te intermittent, Cs continuous deposition until the final maximum QE

### QE>6% @ 265nm



10

0

0

20

15

Time (h)

25

### Te intermittent, Cs continuous deposition



Acta Phys. Sin. Vol. 71, No. 17 (2022) 178501



### **QE of three typical Cs-Te photocathodes**













		Substrate	Preparation method	QE@ Preparation chamber	QE@ Suitcase
SHINE	1	Мо	Te, Cs Sequential	8%@255nm	11%@255nm
	2	Мо	Te Intermittent, Cs continuous	10.5%@255nm	15%@255nm
	3	Cu	Te Intermittent. Cs continuous	5%@255nm	7%@255nm

# **Photocathode transport**

Photocathode preparation system

Photocathode suitcase (Ultra high vacuum, 1km)

### Photocathode loading system

Photocathode VHF electron gun



Cathode lab



Suitcase unload

~1 km distance



Cathode load lock @Injector tunnel 15

# Photocathode emission in SHINE gun

### Photoelectron beam commissioning started on 2023.12.01

• 2023.12.03, 1<sup>st</sup> photoelectron beam of 200 pC @10 Hz



### **SHINE** First beam @control room

200 pC beam faraday cup signal

### **Photocathode measurement at SHINE gun**

### Photoathode emission curve, QE and thermal emittance

• ~20 ps FWHM, 0.25 mm rms (Gaussian laser)



## **Photocathode measurement at SHINE gun**

- The QE map of the Cs-Te photocathode
- The Cs-Te photocathode can operate for a long lifetime in the SHINE VHF electron gun at 50pC and 100pC



# **Summary**

- The design, assembly, and debugging of the photocathode system was finished.
- Two Cs-Te recipes were developed, and the QE is typically >5%@265nm.
- 1 MHz beam was generated at the SHINE gun.
- Future plans
  - Further optimize the cathode recipe based on the gun operation results (thermal emittance, lifetime, dark current, QE uniformity...).
  - Explore other high QE photocathodes (UV and green photocathodes).
  - Study on the prepared photocathode properties.





# Thank you for your attention!!!